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Dehalogenation and Coupling of a Polycyclic Hydrocarbon on an Atomically Thin Insulator

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3 Catalytic activity is of pivotal relevance in enabling efficient and selective synthesis processes.
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5 Recently, covalent coupling reactions catalyzed by solid metal surfaces opened the rapidly
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7 evolving field of on-surface chemical synthesis. Tailored molecular precursors in conjunction
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9 with the catalytic activity of the metal substrate allow the synthesis of novel, technologically
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11 highly relevant materials such as atomically precise graphene nanoribbons. However, the
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13 reaction path on the metal substrate remains unclear in most cases and the intriguing question is
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15 how a specific atomic configuration between reactant and catalyst controls the reaction
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17 processes. In this study, we cover the metal substrate with a monolayer of hexagonal boron
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19 nitride (*h*-BN), reducing the reactivity of the metal, and gain unique access to atomistic details
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21 during the activation of a polyphenylene precursor by sequential dehalogenation and the
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23 subsequent coupling to extended oligomers. We use scanning tunneling microscopy (STM) and
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25 density functional theory (DFT) to reveal a reaction site anisotropy, induced by the registry
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27 mismatch between the precursor and the nano-structured h-BN monolayer.
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38 KEYWORDS

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41 on-surface reaction, scanning tunneling microscopy, PAH, porous graphene, hexagonal boron
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43 nitride, boronitrene, nanomesh
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3 An atomically thin layer of insulating *h*-BN is a structurally analogous counterpart for
4 graphene – a single layer of sp^2 -hybridised carbon atoms¹ – matching the graphene lattice almost
5 perfectly with a small mismatch of approx. 2%. Currently, the fabrication of two-dimensional
6 materials follows two main approaches: *i*) the bottom-up synthesis by substrate supported
7 chemical vapor deposition (CVD) with suitable precursors and *ii*) the top-down approach by
8 exfoliation. The assembly of graphene/*h*-BN heterostructures, leading to novel devices or
9 devices with enhanced performance, usually relies on elaborate, sequential transfer processes of
10 the produced layers.² The main obstacles are possible misalignment, introduction of defects and
11 contaminations resulting from transferring layers that are just one atom thick. Only recently, the
12 direct CVD growth of graphene on *h*-BN was demonstrated, offering superior properties.³⁻⁵
13 However, the growth conditions are harsh (long exposure time, high temperatures, several
14 cycles, etc.). Metal substrates are favored, because of their high catalytic activity,⁶ but they have
15 the disadvantage that they strongly alter the properties of the grown layers, which therefore
16 cannot be directly used for electronic device fabrication.

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37 A common motif in on-surface chemical reactions is the activation of a precursor, the
38 intermittent complex formed between precursor and substrate, and finally the coupling reaction.⁷
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41 A long-standing question is the impact of the specific atomic configuration between substrate
42 and reactant on the catalytic efficiency and how does the specific atomic arrangement change the
43 site activity and therefore influence the reaction pathways, energies and reaction yield? Thanks
44 to recent advances in surface science, we are witness of a tremendous progress in the
45 understanding and development of on-surface chemical reactions and in the fabrication of
46 nanostructured systems.⁷⁻⁹ A widely used reaction in this context is derived from Ullmann
47 coupling,^{10,11} where the reactive partners are created by dehalogenation of aryl-halide precursors,
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3 which subsequently undergo aryl-aryl coupling.¹² Recent examples of this are the formation of
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5 graphene nanoribbons and porous graphene on metal substrates.¹³⁻¹⁵ The synthesis of porous
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7 graphene is based on the molecular precursor 5,5',5'',5''',5''''',5''''''-hexaiodo-cyclohexa-m-
8
9 phenylene (I₆-CHP, *cf.* inset in Fig. 1a for chemical structure), which dissociates all its iodine
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11 atoms on Cu(111), Ag(111) and even Au(111) already at room temperature.¹⁵ The catalytic
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13 activity is so high that site specific effects are difficult to study and do not seem relevant for the
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15 synthesis process. This situation can be expected to be different for a surface supported, ultra-
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17 thin insulating spacer layer like monolayer *h*-BN, in analogy to graphene sometimes referred to
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19 as boronitrene.¹⁶ The lack of electronic states close to the Fermi level will reduce the catalytic
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21 activity, whereas the ultimate thinness still allows the dehalogenation process to be studied by
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23 STM. Furthermore, the interaction between the metal and *h*-BN layer generates distinct
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25 superstructures that can be adjusted by a variation of the underlying metal (Ni,¹⁷ Pt,¹⁸ Cu,¹⁹ Rh
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27 and Ru,^{18,20-26} Fe and Cr^{27,28}). On Rh(111) the *h*-BN forms a highly corrugated “nanomesh”
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29 consisting of regions with strong bonding, dents (sometimes referred to as pores), separated by
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31 suspended wire regions, where the *h*-BN-Rh(111) interaction is weaker.^{18,23,26,29-31} Consequently,
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33 the structure of the corrugated *h*-BN is a superposition of the 0.25 nm BN lattice and the network
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35 of dents with a lattice constant of 3.2 nm.
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44 As we will show in the following, deposition of I₆-CHP on the corrugated *h*-BN leads to a
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46 distinct adsorption geometry imposing a non-equivalency on the six iodine sites of the molecule,
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48 which is not intrinsic to the free I₆-CHP. The adsorption geometry, sequential dehalogenation
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50 and the subsequent coupling of I_x-CHP species are analyzed by low-temperature scanning
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52 tunneling microscopy (LT-STM at 5.5 K) and density functional theory (DFT). Our experimental
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54 and theoretical findings show that the dehalogenation process is surprisingly strongly influenced
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3 by the substrate and they shed light on the challenges of growing bottom-up designed
4 nanostructures directly on an insulating substrate, being indispensable for efficient application in
5 electronic, optic and spintronic devices.
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10 11 12 **Results and discussion**

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16 **The nanoscale petri dish for molecules.** Figure 1a displays an UHV LT-STM image with low
17 coverage (approx. 0.15 ML) of I₆-CHP deposited onto the corrugated *h*-BN (kept at RT during
18 deposition). Empty dents are imaged as dark depressions.^{18,23} while the adsorbed molecules
19 exhibit a six petal flowerlike appearance originating from the apparent D₆ symmetric structure of
20 a single I₆-CHP. All molecules occupy single dents and are well-separated from each other and
21 follow the same registry as the superstructure of the corrugated *h*-BN. This situation is entirely
22 different compared to molecules on other insulating thin films typically used in STM – like alkali
23 metal salts (NaCl, KCl, etc.) on metals. The rather homogenous structure of these dielectric
24 spacers is of manifold advantage to studying individual molecules.³²⁻³⁴ However, the adsorption
25 energy landscape for molecular species usually shows only subtle corrugation and already at low
26 coverage (well below a closed monolayer) immediate 2-dimensional domain formation is
27 observed, with molecular close-packing or even aggregation into 3-dimensional structures
28 similar to single crystal insulators.^{35,36}
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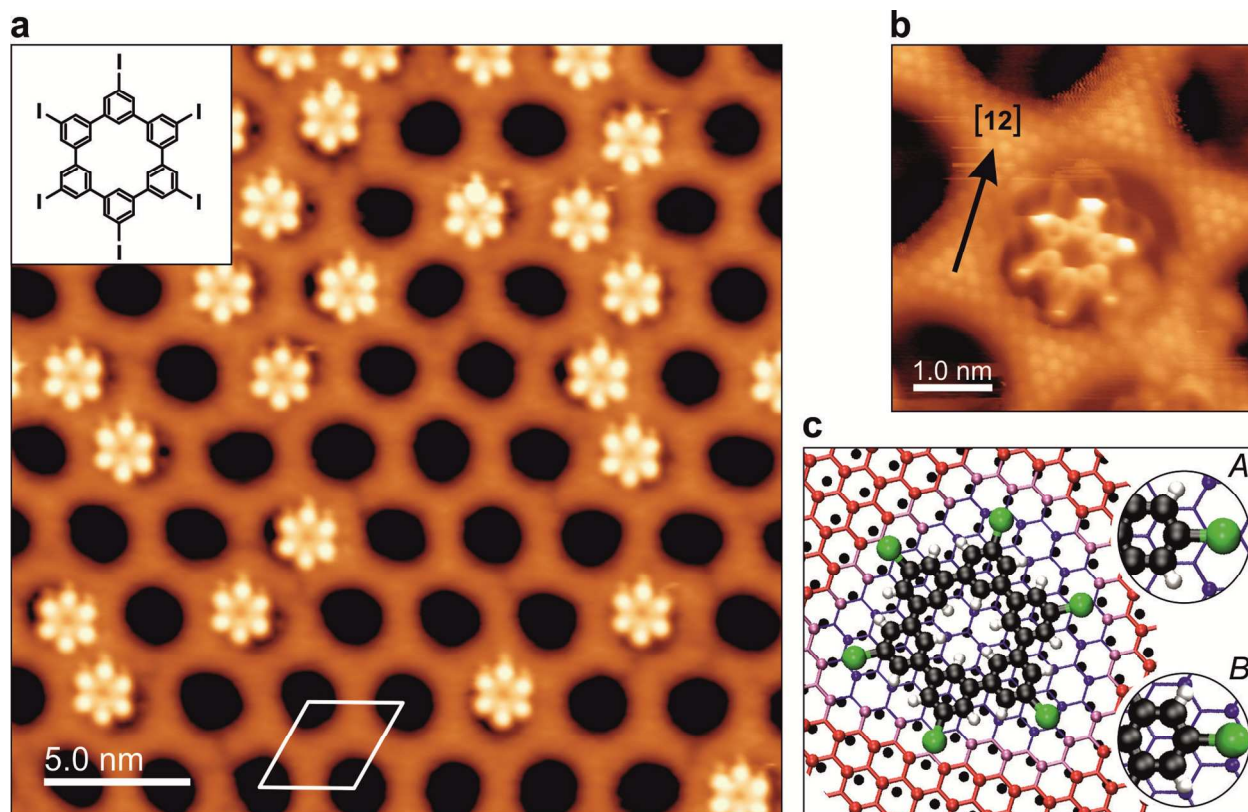


Figure 1: Molecule I_6 -CHP and the corrugated h -BN. **a**, STM image (-1.70 V, 40 pA) of I_6 -CHP molecules occupying some of the dents of the corrugated h -BN (low coverage of 0.15 ML, height scale: $\Delta z = 170$ pm, inset: molecular structure). **b**, High resolution STM image (-1.2 V, 32 pA, (height scale: $\Delta z = 170$ pm)) of a single molecule, revealing internal contrast of the h -BN layer and submolecular contrast of the molecule. **c**, Ball and stick model of the DFT derived position and orientation of the I_6 -CHP in the dents of the corrugation (boron atoms of h -BN lattice enlarged; dent indicated by color coding; black dots indicate top layer of rhodium atoms). The two insets show the different registries for the carbon-iodine bond: hollow position = A site; on top boron = B site (rhodium atoms are omitted for clarity reasons).

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3 Here on the corrugated *h*-BN, all intermolecular distances are well defined by the
4 superstructure lattice of the dents, which are large compared to those found in close-packed I₆-
5 CHP domains. Therefore, the intermolecular interactions between neighboring molecules are
6 negligible and the species can be treated as isolated molecules, interacting solely with the
7 *h*-BN/metal substrate. Figure 1a shows the regular adsorption geometry of I₆-CHP molecules
8 within the dents. Two major observations can be drawn immediately: *i*) the molecules
9 systematically adsorb close to the rim rather than at the center of a dent (the center-center
10 distance between molecule and dent is 0.48±0.09 nm) and *ii*) a clear preferential orientation for
11 I₆-CHP in the dent can be observed. Within the measurement accuracy of 1° all molecules are
12 perfectly oriented along the [12] direction of the *h*-BN corrugation. The preferential orientation
13 is confirmed by the DFT calculations (*cf.* Supplementary Information) and proves the existence
14 of a specific registry of the molecule and the *h*-BN lattice. While the geometry of an I₆-CHP
15 molecule in the gas phase, as optimized by DFT, exhibits D₃ symmetry of alternating up-down
16 tilted phenyl rings, this buckling diminishes on the substrate, which is consistent with STM
17 images, where the molecules appear as planar (*cf.* high resolution STM imaging in Fig. 1b).

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39 The shape and size of the STM image of the molecule (outer diameter approx. 15 Å) clearly
40 indicate that all the six iodine atoms are still covalently bonded to the aromatic macrocycle. This
41 is in strong contrast to the case of I₆-CHP on metals, where the iodine atoms already dissociate at
42 room temperature, leaving a sizeable space between the iodine atoms and the molecular
43 remnant.^{14,15} The non-dissociated I₆-CHP molecules on the *h*-BN confirm the reduced catalytic
44 activity of BN already at the monolayer thickness on a metallic substrate. Detailed analysis of the
45 atomic contrast of *h*-BN and the I₆-CHP position in the high resolution STM images and DFT
46 calculations suggest that the molecules are centered above the nitrogen atoms (*cf.* Fig. 1c), with
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3 the I₆-CHP's carbon atoms on-top of boron or on hollow sites of the *h*-BN. This yields to two
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5 alternating, non-equivalent sites of the C-I groups with respect to the *h*-BN substrate, reducing
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7 the apparent 6-fold symmetry of the I₆-CHP to an effective 3-fold one. As shown in Fig. 1c, the
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9 site denoted by *A* is characterized by the carbon atom of the C-I group located on top of a *h*-BN
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11 hollow site. For the *B* site, the carbon atom is located on top of a boron atom.
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17 **Tip-induced dehalogenation of a single molecule**

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20 The fact that the I₆-CHP stays intact when deposited onto the corrugated *h*-BN layer offers a
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22 unique opportunity to study the dissociation of its iodine atoms individually and in detail. Under
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24 some tunneling conditions, we observed a low yield, spontaneous STM tip induced
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26 dehalogenation of the I₆-CHP. Figure 2 displays several stages of a typical dehalogenation
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28 sequence of a single I₆-CHP molecule, exhibiting three remarkable features: *i*) the iodine atoms
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30 dissociate at alternating positions around the molecule, *ii*) the dehalogenation comes to a halt
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32 after removing three iodine atoms and *iii*) the dissociated iodine atoms and the molecule can stay
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34 in close proximity within one dent. Since in the gas phase the iodine dissociation energy is the
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36 same irrespective of the iodine sites and also of the number of already dissociated iodine atoms,
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38 the deviations seen here are obviously an effect of the interaction with the substrate, (2 eV from a
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40 DFT calculation, *cf.* Supplementary Information). In other words, the free I₆-CHP molecule does
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42 not possess intrinsic site correlation with regard to the dehalogenation process. As a
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44 consequence, neither I₃-CHP species (alternating 5',5''',5''''-I₃-CHP or continuous 5''',5''''',5''''''-
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46 I₃-CHP) should exhibit an accentuated stability.
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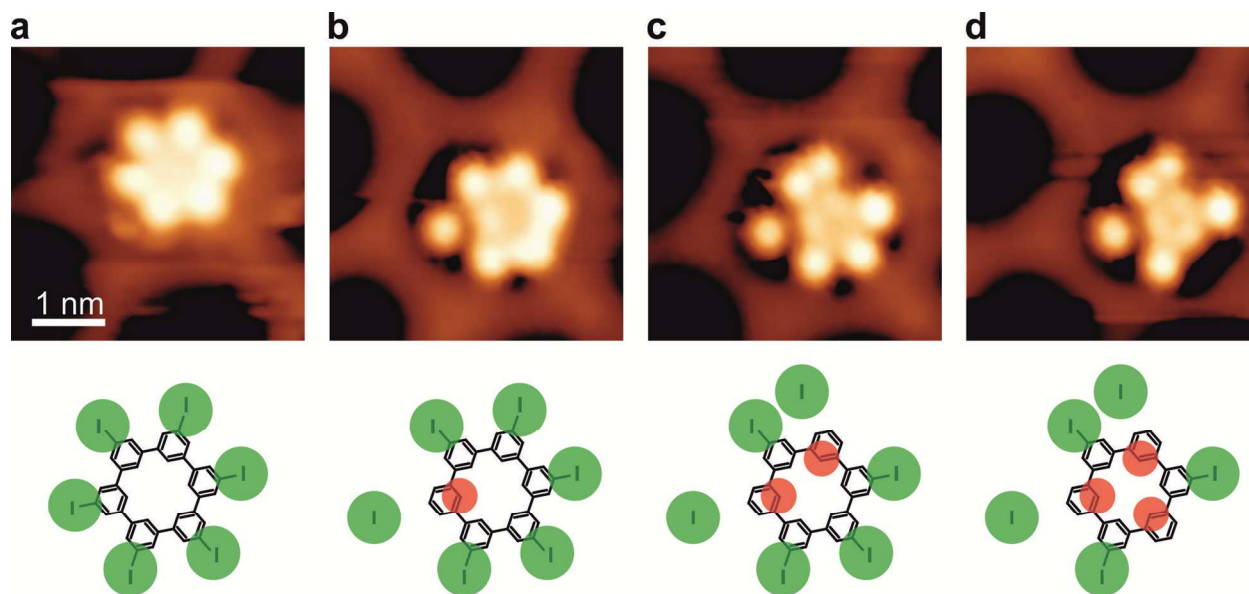


Figure 2: Sequence of STM images during tip-induced iodine dissociation. a-d, Close up STM images (top) and illustrative diagrams (bottom) of the sequential dehalogenation (height scale: $\Delta z = 170$ pm). a, The six lobes of the intact molecule (1.1 V, 100 pA) are formed by iodine atoms (schematically shown in green). b-d, The continuously applied tip-sample current (1.5 V, 100 pA) during on-going STM scans leads to the dissociation of iodine atoms from I_6 -CHP at specific positions (*i.e.* the B sites: b, at 5''''', c, at 5', and d, at 5'''). The actual sequence is random. The highest accessible state of dissociation by this approach is the I_3 -CHP (d). The dissociated iodine atoms can stay within the dent without affecting the molecular remnant or be removed by the tip (d). Please note the appearance of small protrusions (schematically drawn in red) close to the center of the molecule after removing the corresponding iodine atom.

On the corrugated *h*-BN instead, the registry between molecule and substrate lifts the equivalency between the different iodine sites. The regularly observed case is that the iodine atoms subsequently dissociate at positions 5',5''', or 5'''' (cf. Fig. 2b to d) – which corresponds to the B sites of the previously assigned adsorption geometry (cf. Fig. 1c). The investigation of

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3 numerous STM tip-induced dehalogenation events shows that the sequence among the three
4 *B* sites is random and does not involve detectable movement of the molecule. Additionally, once
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8 the covalent iodine-carbon bond is broken, the separated lobe of the detached iodine atom
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10 appears accompanied by a protrusion on the CHP backbone close to the newly formed radical
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12 position. As this protrusion is visible at STM bias voltages well within the HOMO-LUMO gap,
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15 we attribute it to a change in the conformation of the molecule rather than to an electronic effect.
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17 As we will discuss later on, DFT calculations show that the conformational change is caused by
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19 a bond formation of the radical site with the underlying boron atom. Such a bond locks the
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21 molecule in position and consequently favors the remaining alternating sites – which are now
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24 locked above boron atoms – for dehalogenation, *i.e.*, dissociation at all the *B* sites.
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27 However, in some rare cases the first iodine atom of I₆-CHP dissociates at an *A* site. Only then,
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29 the dehalogenation is accompanied by a small but well observable relocation of the molecule (cf.
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31 Supporting Fig. S2). This shift was first revealed by the DFT structure optimization of the
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33 dehalogenated molecule and afterwards recognized in the experiments. Indeed, the shift is
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35 necessary to form the carbon-boron bond, since the carbon atom is initially, *i.e.* before
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37 dehalogenation, on top of a hollow site. In the new position and consequently new registry to the
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39 substrate, the options for further dehalogenation of the molecule are limited and the opposing
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41 iodine atom is predominantly dissociated. The two bonds between molecule and substrate
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43 effectively suppress additional dehalogenations at the remaining iodine sites, *e.g.* a stable
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45 5',5'',5''',5''''-I₄-CHP results. Summarizing, complete dissociation at *B* sites – forming 5,5'',5''''-
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47 I₃-CHP – is by far the most commonly observed dehalogenation state and also marks the limit of
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49 tip-induced dehalogenation during continuous STM imaging. In cases, where we observe
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51 dehalogenation at an *A* site, it is predominantly followed by the iodine abstraction at the
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3 opposing *B* site. In these cases the tip-induced dehalogenation stops with the formation of
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5 I₄-CHP.
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10 **Dehalogenation by thermal annealing**

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12 In order to further corroborate our findings on the orientation and site selectivity of the iodine
13 abstraction, we conducted thermally activated dehalogenation experiments. Figure 3a shows the
14 LT-STM image after heating the sample to approx. 500 K for 15 min. A large variety of
15 molecular species is visible, differing in the degree of dissociation (number of radical sites) and
16 the specific position where the iodine atoms dissociated from. Unlike in the tip-induced case,
17 here the dissociated iodine usually cannot be found in the dents with the molecule. The atoms
18 generally desorb from the surface or aggregate forming iodine islands. Despite the different
19 stages of dehalogenation nearly all molecular species are oriented along the [12] direction of the
20 *h*-BN corrugation. Counting the created I_{*x*}-CHP species over a larger field of view (*cf.* supporting
21 figure S1), more than 95% of all observed dehalogenated positions turn out to be at *B* sites of the
22 molecule-*h*-BN registry. This motif of preferred dehalogenation sites gets even more evident
23 when three iodine atoms dissociate, leading to the three-fold symmetric I₃-CHP with only *B* site
24 dissociations. It nicely confirms the observation made before that the first dissociation at the
25 I₆-CHP molecule constrains the available sites for subsequent dehalogenation steps.
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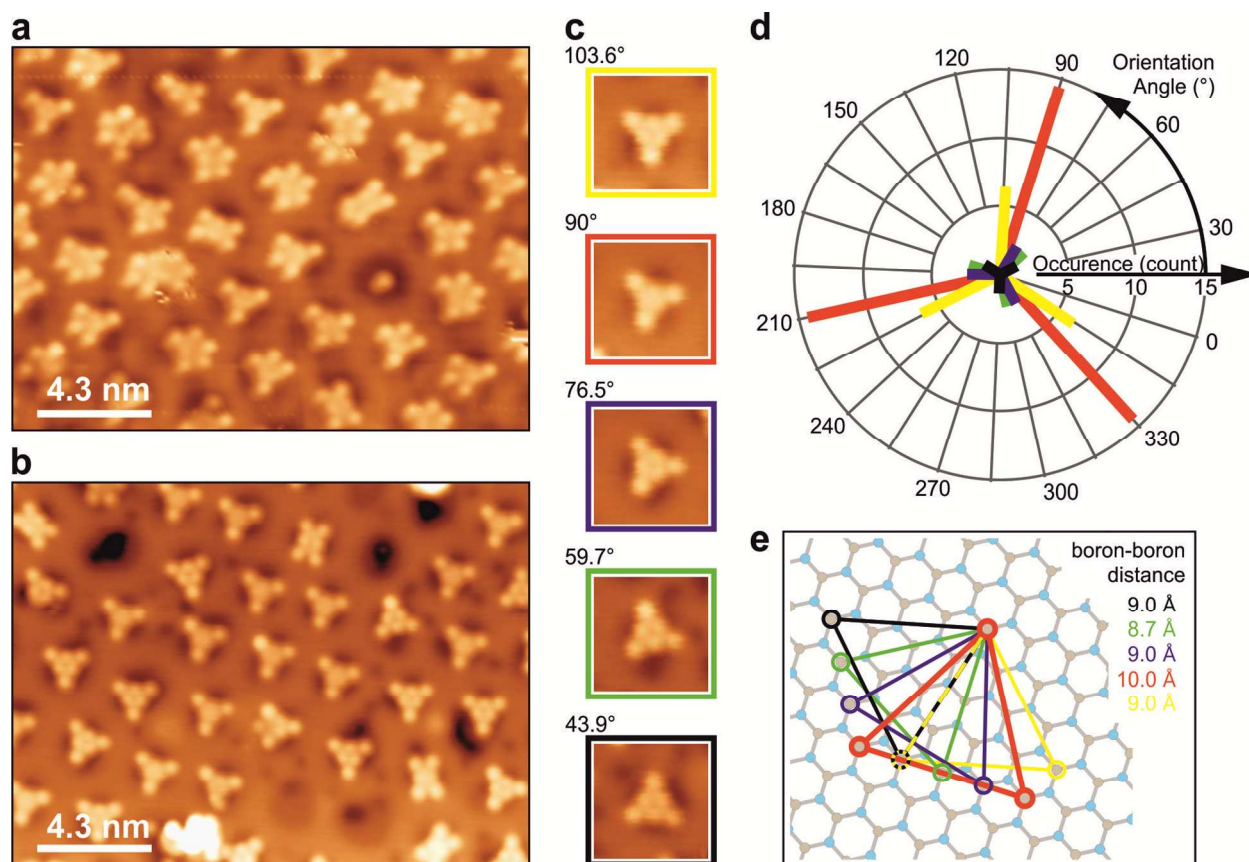


Figure 3: Iodine dissociation by thermal annealing. **a**, LT-STM image (1.2 V, 23 pA, height scale: $\Delta z = 170$ pm) after annealing the sample to 500 K for 15 min. Either 1, 2, or 3 iodine atoms have been dissociated per CHP molecule. Nearly all of the resulting species are oriented in the same direction, independent of the number of dissociated iodine atoms. **b**, LT-STM image (2 V, 40 pA, height scale: $\Delta z = 170$ pm) after treatment at 680 K for 30 min, leaving almost exclusively I_3 -CHP molecules. **c**, Zoomed view of selected species of (b) including angles of rotation, showing differently pronounced protrusions close to the center of I_3 -CHP molecules, presumably due to the formation of carbon-boron bonds after iodine dissociation. **d**, Detailed analysis of the orientations of dissociation sites in I_3 -CHP in (b) relative to the corrugation lattice of the *h*-BN on Rh(111) (colors refer to the specific orientations in c). The preferred orientation is along the [12] direction (red bars). **e**, Geometric correlation between an undisturbed *h*-BN

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3 lattice (lattice constant 2.5 Å) and the boron atoms presumably bonded to I₃-CHP (molecule
4 omitted for clarity). A smaller separation between these boron atoms corresponds to a stronger
5 tilt of the connected phenyl rings (triangles act as guides for the eye using the same colors as in
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8 (c) and (d); red for regular dissociation in [12] direction).
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16 The preference becomes less stringent under prolonged annealing conditions at higher
17 temperatures, where essentially I₃-CHP species are formed, but their rotational alignment within
18 the dents is no longer limited to the exclusive [12] direction (*cf.* LT-STM image after thermal
19 treatment at 680 K for 30 min. in Fig. 3b). This can be related to an increased mobility of the
20 molecules at elevated temperatures allowing the dissociation at previously inaccessible sites on
21 the *h*-BN lattice. Yet, the observable orientations of the I₃-CHP molecules are not random
22 (exemplary molecules and their occurrence are shown in Fig. 3c and d, respectively, with
23 predominant 90° orientation, *i.e.* alignment in the [12] direction) and the radical positions can be
24 tentatively related to the boron sites of the *h*-BN (Fig. 3e). In cases where the boron-boron
25 distance becomes smaller (all cases different from the [12] orientation) the protrusions are more
26 pronounced (*cf.* green and red in Fig. 3c), indicating a stronger tilt of the corresponding phenyl
27 rings. The significance of this circumstance will be discussed in the light of the DFT results.
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47 **Ab initio simulation of dehalogenation**

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49 To gain a deeper understanding of the unexpected site selectivity of the dehalogenation process
50 and its apparent persistence even at elevated temperatures, we need to answer the question,
51 which atomistic processes determine the peculiarity of the dehalogenation sites. So far we
52 showed that the registry between molecule and substrate yields two different configurations for
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3 the iodine atoms (*A* and *B* sites) in alternating sequence on the I₆-CHP. While the DFT derived
4 total dissociation energy for the first iodine atom from an I₆-CHP molecule on *h*-BN/Rh(111)
5 exhibits only a small variation between *A* and *B*, the accompanying reorganization energies for
6 the CHP remnant on the corrugated *h*-BN layer vary strongly with the actual iodine site.
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8 Evaluating the dissociation process shows that breaking the iodine-carbon bond is indeed
9 accompanied by a bond formation between the unsaturated carbon atom of the iodine-free phenyl
10 ring and the underlying boron atom of the *h*-BN. This bond instantly forms at *B* sites without
11 moving the molecule (*cf.* Fig. 4c), while dissociation at an *A* site induces a displacement of the
12 CHP remnant in order to let the unsaturated C atom approach the closest boron atom of the
13 substrate and form the bond (Fig. 4a). This not only results in higher reorganization energies,
14 *e.g.*, altered geometry of the dent, but also changes the registry between the CHP remnant and
15 the substrate. Consequently, subsequent dehalogenation steps become less favorable. Figure 4e
16 summarizes the DFT dissociation energies for some selected sequences, where the pure *B* site
17 dissociations (*B-B-B* in Fig. 4e) form the energetically most favorable path of any triiodo-CHP
18 final configuration.
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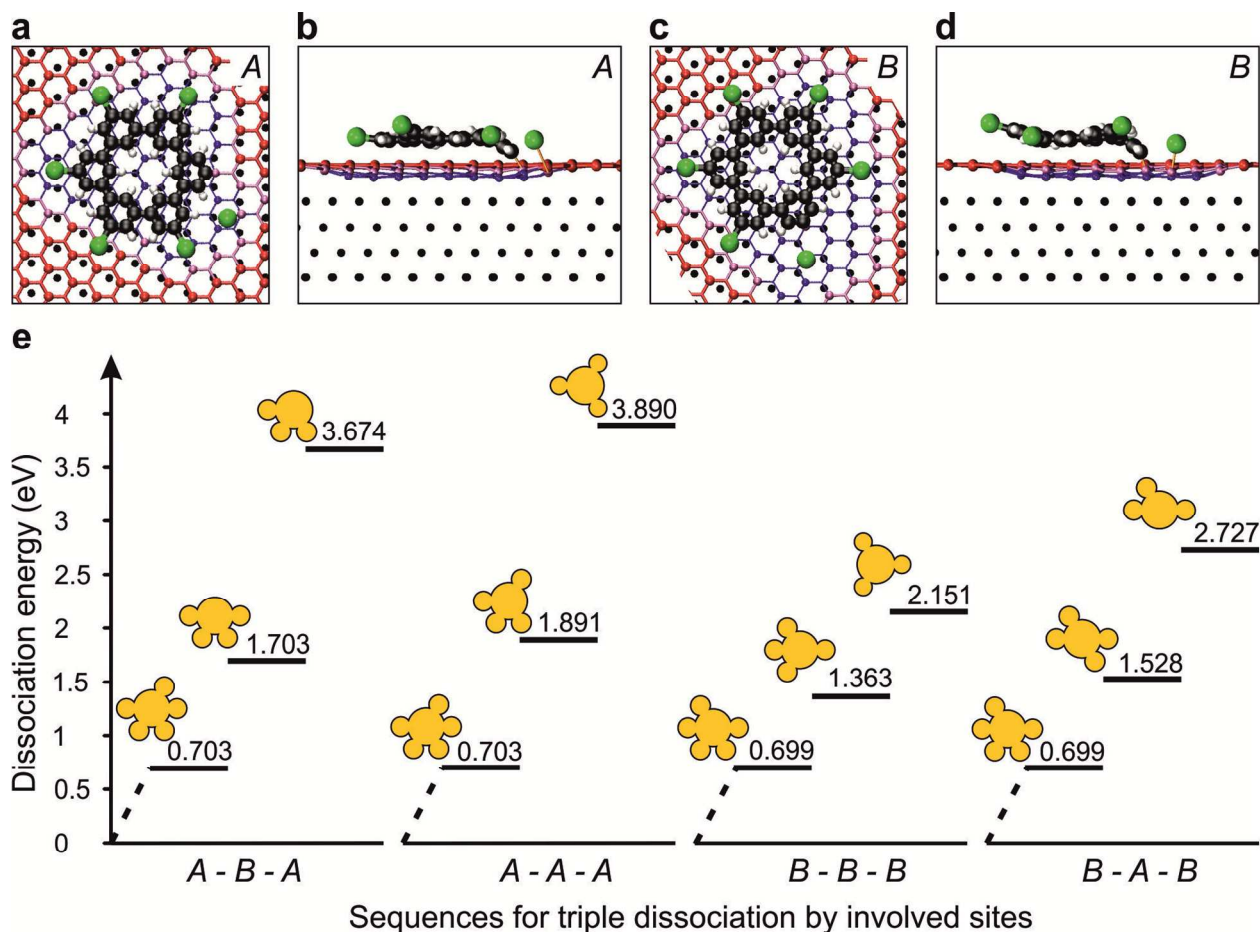


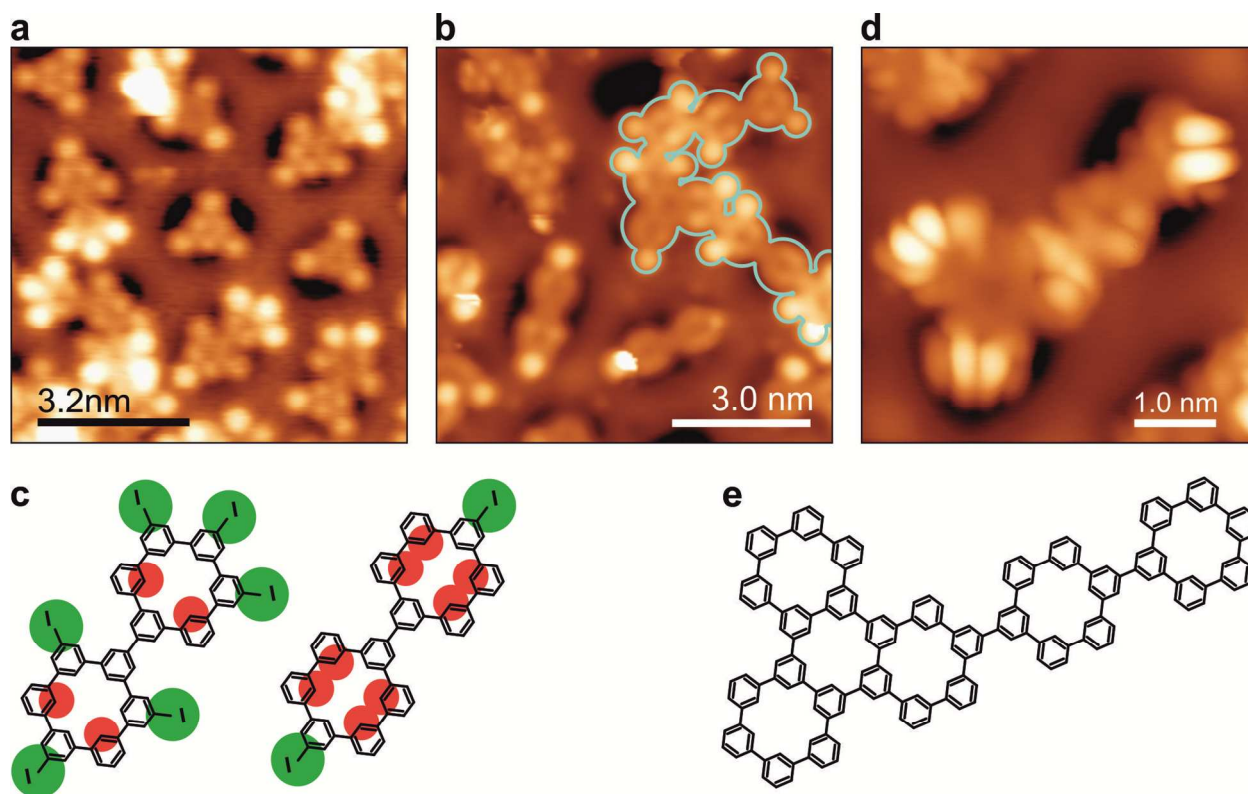
Figure 4: Dehalogenation by *ab initio* simulations. **a**, Dissociation at an *A* site resulting in a shift of the remaining molecule in the dent due to formation of a carbon-boron bond (CHP center no longer above nitrogen atom of *h*-BN). **b**, Side view indicating a strong tilt of the corresponding phenyl rings induced by the carbon-boron bond. **c**, After a dissociation at a *B* site, the molecule is still centered at the nitrogen atom, *i.e.*, no shift of the molecule within the dent. The side view shows a similar tilt of the corresponding phenyl ring (d). **e**, Dissociation energies (dissociated iodine atoms placed on wire) and illustrative pictograms of selected sequences representing the subsequent dehalogenation of I₆-CHP on *h*-BN, starting from a fully halogenated molecule. The energies given represent the sum of changes in total energy during subsequent dissociations necessary to create a certain I₃-CHP species.

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6 The formation of a carbon-boron bond during dehalogenation slightly lifts the boron atom, still
7 preserving the integrity of the *h*-BN lattice. The corresponding phenyl ring significantly tilts by
8 35° out of the molecular plane. This geometrical change explains the small protrusion appearing
9 in the STM images close to the center of the CHP remnant towards the dehalogenated site (*cf.*
10 Fig. 2). The lock-into-position of the molecule by the carbon-boron bond can only be overcome
11 at elevated annealing temperatures, leading to molecule configurations with small-angle rotation
12 to neighboring boron sites. These orientations of the molecule, which are off the [12] direction,
13 are however not random but correspond again to well-defined geometrical positions of the
14 carbon radical sites bonding to boron atoms of the *h*-BN (Fig. 3c). The difference in distance
15 between the involved boron atoms (ranging from approx. 8.7 Å to 10 Å for the different
16 rotational states) reveals itself in a varying accentuation of the STM-topographic substructure at
17 the position of the cyclohexa-*m*-phenylene macrocycle. In other words, the registry with the
18 underlying *h*-BN lattice defines the tilting angles of the phenyl rings as the molecular
19 conformation must adapt itself to the shorter distance between the corresponding boron atoms
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43 **Oligomer formation by covalent coupling**

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46 So far, we have shown that for temperatures up to 680 K only approximately half of the iodine
47 atoms are dissociated from I₆-CHP and the question arises whether controlled, direct aryl-aryl
48 coupling between two dehalogenated molecules is possible. The barrier formed by the wire
49 region between neighboring dents is conquerable by a higher surface coverage of I₆-CHP
50 molecules, *i.e.*, decorating the wire regions of the *h*-BN corrugation. This raises the probability
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3 that dehalogenated sites of neighboring molecules get in sufficiently close proximity of each
4 other for the formation of dimers (*cf.* Fig. 5a). However, the annealing temperature of 550 K
5 leaves a significant number of iodine atoms covalently bonded to the CHP core, some appearing
6 significantly brighter in STM topography, because they are pushed onto the wire region of the
7 corrugated *h*-BN as the restricted size of a dent cannot accommodate an entire dimer. The centers
8 of the dimers exhibit a similar substructure of bright protrusions next to the dehalogenated sites
9 as observed for monomers, due to tilted phenyl rings, indicating the presence of carbon-boron
10 bonds (Fig. 5c). Reducing the number of bonded iodine atoms and facilitating the formation of
11 extended oligomers requires annealing temperatures above 800 K. Consequently, a large variety
12 of species and their orientation on the boron nitride can be observed.



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54 **Figure 5: Covalent coupling of CHP species at different temperatures.** a, STM image
55 (-1.5 V, 30 pA) of a high coverage sample (approx. 1 ML) after treatment at 550 K for 20 min.
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3 Not only the expected I₃-CHP molecules have formed but various dimers with different iodine
4 terminations are visible. **b**, STM image (-1.5 V, 30 pA) after treatment at 800 K for 30 min.
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6 Dimers and larger aggregates (light blue outline) have formed, but despite the high temperature
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8 still contain a notable number of iodine atoms. **c**, Illustrative sketch of two exemplary dimers
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10 observed in (a) and (b) (iodine atoms are shown in green, protrusion by tilted phenyl rings are
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12 highlighted in red). **d**, STM image (2.2 V, 20 pA) of a CHP oligomer coupled by high
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14 temperature treatment at 850 K for 30 min. The chain of coupled rings lies across two dents of
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16 the *h*-BN corrugation. **e**, Molecular structure of the CHP-based core of the oligomer shown in
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In Fig. 5b, almost iodine free dimers exist alongside extended oligomers. The outlined example is comprised of 9 CHP units and spans across several unit cells of the *h*-BN corrugation. The strong variation in appearance along the whole structure does not only originate from steric hindrance induced by the included iodine atoms, but also from bending across the wire region of the corrugation. Only at annealing temperatures of 850 K was it possible to produce iodine free oligomers as shown in Fig. 5d, where a chain of 5 connected CHP macrocycles can be seen (*cf.* Fig. 5e for structure of the CHP core). The fact that the structure bridges a wide area that exhibits strong variations of the surface potential²² might contribute to the peculiar contrast in STM topography at the borders of the structure. The reason is that the locally varying surface potential can lead to an asymmetric shape of the frontier orbitals whose influence on the STM becomes important when scanning at high biases on insulating substrates.³²⁻³⁴

Conclusion

In-depth understanding of on-surface chemical reactions between molecular species and the underlying catalytic substrate with sub-molecular resolution is vital to the synthesis of active nanostructures for organic electronics. This is particularly the case for insulating substrates, which are technologically highly relevant but have not been widely investigated in this context. With the results presented here, we can directly correlate the adsorption position of the molecule and the possibility to produce the dehalogenated species necessary for the aryl-aryl coupling. The registry and unexpectedly strong interaction between the substrate and the molecules impose specific stable dehalogenated radical configurations. In the case of the I₆-CHP on the corrugated *h*-BN on Rh(111) this yields a large span in temperatures from the onset of dehalogenation at 500 K to full dehalogenation and coupling at 800 K. This is in strong contrast to metallic substrates like copper, silver or gold where full dehalogenation occurs already at room temperature, and also to the molecule in gas phase, where the dehalogenation sequence of the I₆-CHP is fully uncorrelated. In this respect it would be too simple to picture the effects of the *h*-BN only as an isotropic, reduced catalytic activity. We have shown that the interaction of the radical with the *h*-BN substrate is highly site specific and governs the dehalogenation sequence of the molecule. This poses a challenge for the controlled coupling. The imposed site selectivity could be of use for spatially precise dissociations towards dedicated reaction pathways. This, in turn, needs the precise matching between the molecule's sites of interest and the lattice constant of the *h*-BN. This substrate itself remains quite unaffected during the reactions and only provides the required bonding sites to stabilize the intermediate molecular species prior to subsequent reactions. Finally, the aryl-aryl coupling – similar to the metal mediated Ullmann coupling – was demonstrated on the insulating substrate. The understanding of these systems is another step

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3 forward towards the design of electronic nanostructures on insulating or on other novel
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5 2-dimensional substrates with reduced catalytic activity.
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10 11 **Methods**

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13 All experiments were performed in a UHV apparatus (base pressure 5×10^{-11} mbar) comprising
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15 a low-temperature scanning tunneling microscope operated at 5.5 K (LT-STM, Omicron). The
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17 rhodium single crystal (Rh(111)) is cleaned by repeated cycles of Ar^+ ion sputtering (750 eV,
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19 grazing incidence) and thermal annealing at 1200 K. Films of h-BN were grown by thermal
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21 dehydrogenation of borazine ($(\text{HBNH})_3$, ~ 50 Langmuir) on the hot metal surface (1100 K)^{23,26,29}.
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23 This is an almost self-limiting process, as the layer formation slows down once the first
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25 monolayer is completed. Subsequently, the sample is annealed at 1100 K for 15 min to promote
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27 uniform layer morphology. The preferential orientation of the h-BN on Rh(111) is deduced from
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29 energy dependent spot intensity analysis in Low Energy Electron Diffraction (LEED).³⁷ The D_{3h}
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31 symmetry given by the hcp- and fcc-hollow sites of the Rh(111) determines the orientation of the
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33 h-BN layer grown on it.³⁰ Afterwards, I_6 -CHP molecules (see Ref. 38 for Synthesis) were
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35 deposited from a Knudsen cell, with a deposition rate of approx. 0.1 ML/min while keeping the
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37 substrate at room temperature. The Pt-Ir-tips were cut and optimised by slight indentation during
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39 usage. The software WSXM was used to analyse the STM images.³⁹
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47 The DFT calculations were performed using the CP2K package (CP2K version 2.3.43; CP2K
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49 is freely available in <http://www.cp2k.org/>) with the mixed Gaussian and plane wave formalism⁴⁰
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51 and periodic boundary conditions. The exchange and correlation functional used was the
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53 revised⁴¹ version of the Perdew-Burke-Ernzerhof (PBE)⁴² function. Long-range dispersion
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55 interactions were included using the DFT-D3 formalism.⁴³ The core electrons were represented
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3 by Goedecker-Teter-Hutter pseudopotentials.⁴⁴ Single- (for Rh), double- (B, N, C and I) and
4 triple- (H and O) Zeta basis set including polarized function were employed to describe the
5 valence electrons. The energy cutoff for the plane wave expansion representation was
6 500 Rydberg. The sampling in the Brillouin zone was made only at the Γ point. Due to the large
7 size of the cell, such sampling is accurate. The size of the cell used in the calculations is
8 32.1195 Å in **a** and **b** directions and 25 Å along the surface normal **c**. This corresponds to a
9 12x12 four layers rhodium slab with a cell parameter of 3.785 Å and an adsorbed 13x13 h-BN
10 monolayer. The dissociation energy is defined as the difference in total energy between the
11 adsorbed, intact molecule and a configuration, where the dissociated iodine atoms are placed on
12 the wire of the nanomesh.
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49 ASSOCIATED CONTENT

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52 **Supporting Information Available:** DFT results on the adsorption position and the
53 dehalogenation in gas phase. Analysis of species created by thermal dehalogenation. This
54 material is available free of charge *via* the Internet at <http://pubs.acs.org>.
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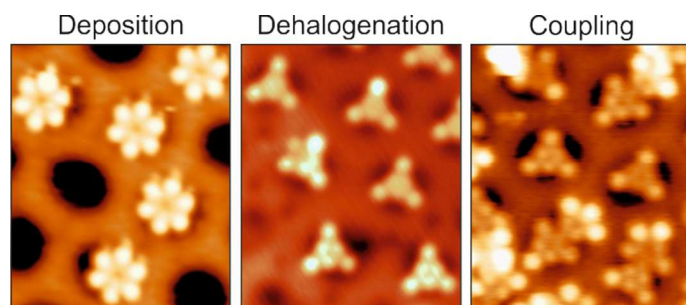
27 **Author Contributions**
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30 T.D. and K.R. performed the STM measurements. T.D., R.W., and O.G. analyzed the data and
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32 discussed the results. J.G.-D., A.P.S., M.I., and J.H. performed the DFT calculations. H.S. and
33
34 K.M. provided the molecules. T.D. and A.P.S. wrote the manuscript with inputs from all other
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36 authors.
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43 **Notes**
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45 † Jaime Gómez-Díaz: Deceased.
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TOC FIGURE



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